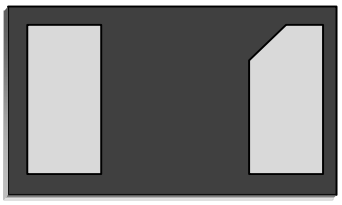
WS03DPMF-BH

Transient Voltage Suppressor

Features

- 700 Watts Peak Pulse Power per Line (t_p=8/20μs)
- Small Body Outline Dimensions
- Protects one I/O or power line
- Working Voltage: 3.3V
- Low Leakage Current



DFN1006-2L

IEC COMPATIBILITY (EN61000-4)

- **IEC 61000-4-2 (ESD) ±30kV (air), ±30kV (contact)**
- **IEC 61000-4-4 (EFT) 40A (5/50ns)**
- **IEC 61000-4-5 (Lightning) 70A (8/20μs)**

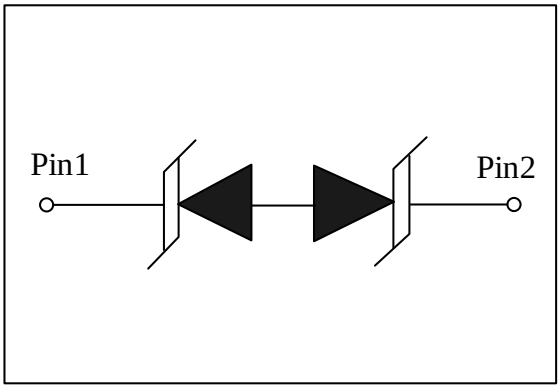
Mechanical Characteristics

- DFN1006-2L package
- Marking : Marking Code
- Packaging : Tape and Reel per EIA 481
- RoHS Compliant & HF
- Device meets MSL1 requirement

Applications

- Cellular Handsets & Accessories
- Personal Digital Assistants (PDAs)
- Notebooks & Handhelds
- Portable Instrumentation
- Digital Cameras

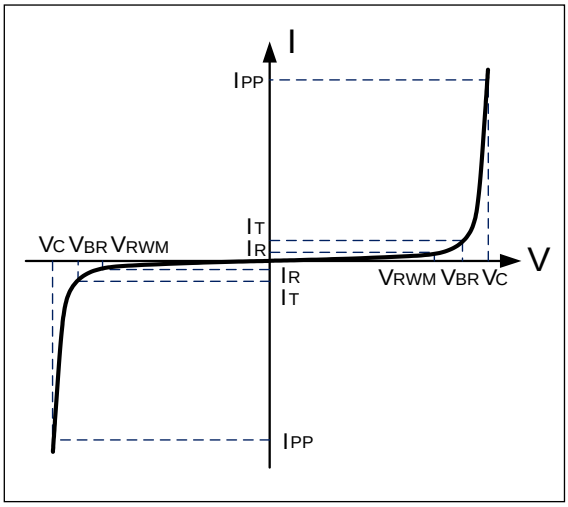
Schematic & PIN Configuration



Absolute Maximum Rating			
Rating	**Symbol**	**Value**	**Units**
Peak Pulse Power (t_p = 8/20μs)	P_{PP}	700	Watts
Peak Pulse Current (t_p = 8/20μs)	I_{PP}	70	A
Operating Temperature	T_J	-55 to + 125	℃
Storage Temperature	T_{STG}	-55 to +150	℃

Electrical Parameters

Symbol	Parameter
I_{PP}	Reverse Stand-Off Voltage
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Reverse Stand-Off Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current



Electrical Characteristics(T=25℃ unless otherwise noted)

WS03DPMF-BH						
Parameter	**Symbol**	**Conditions**	**Minimum**	**Typical**	**Maximum**	**Units**
Reverse Stand-Off Voltage	V_{RWM}				3.3	V
Reverse Breakdown Voltage	V_{BR}	I_T=1mA	3.7			V
Reverse Leakage Current	I_R	V_{RWM}=3.3V			200	nA
Clamping Voltage	V_C	I_{PP}=70A, t_p=8/20μs		8	10	V
Dynamic Resistance[1,2]	R_{DYN}	TLP=0.2/100ns		0.08		Ω
ESD Clamping Voltage[1]	V_C	IPP = 4A, tp = 0.2/100ns (TLP)		4.6		V
ESD Clamping Voltage[1]	V_C	IPP = 16A, tp = 0.2/100ns (TLP)		5.6		V
Junction Capacitance	C_j	V_R =0V, f =1MHz			240	pF

Notes：1、TLP Setting：t_p=100ns, t_r=0.2ns, I_{TLP} and V_{TLP} sample window:t_1=70ns to t_2=90ns.
2、Dynamic resistance calculated from I_{PP}=4A to I_{PP}=16A using “Best Fit”.

Typical Characteristics

Figure 1: Peak Pulse Power Vs Pulse Time

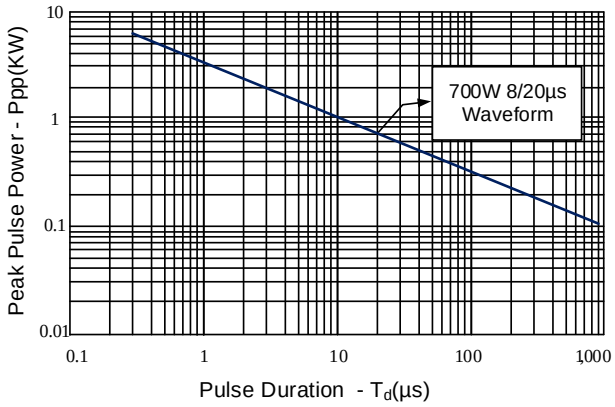


Figure 2: Power Derating Curve

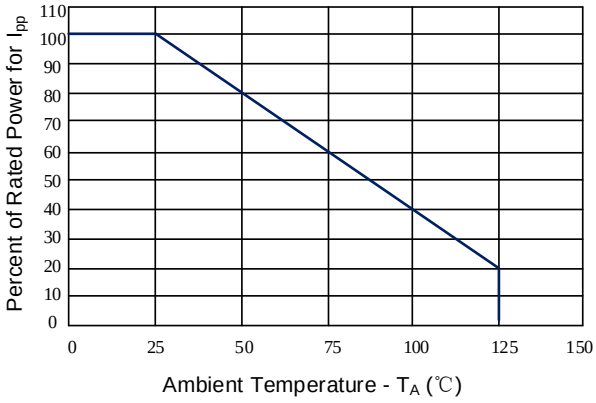


Figure 3: Clamping Voltage vs. Peak Pulse Current

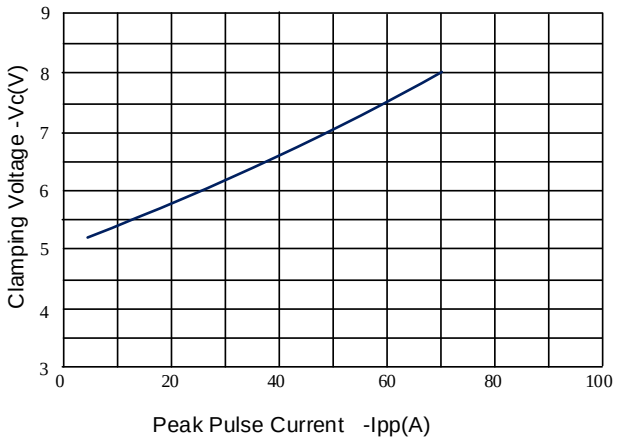


Figure 4: Normalized Junction Capacitance vs. Reverse Voltage

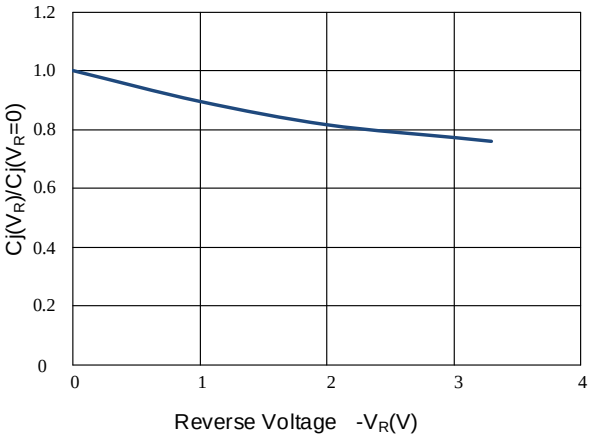


Figure 5: TLP Positive I-V Curve

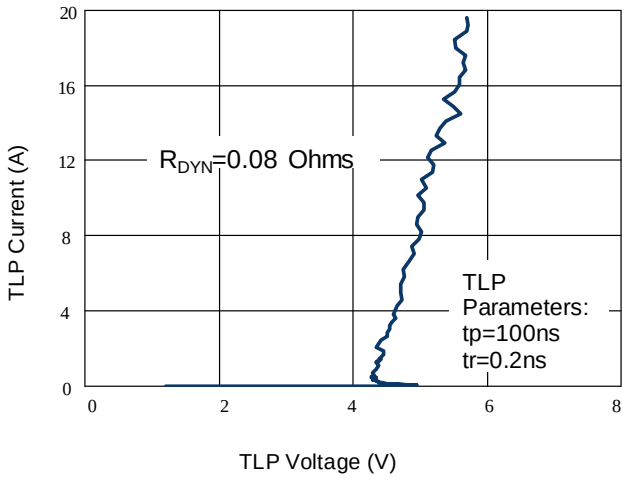
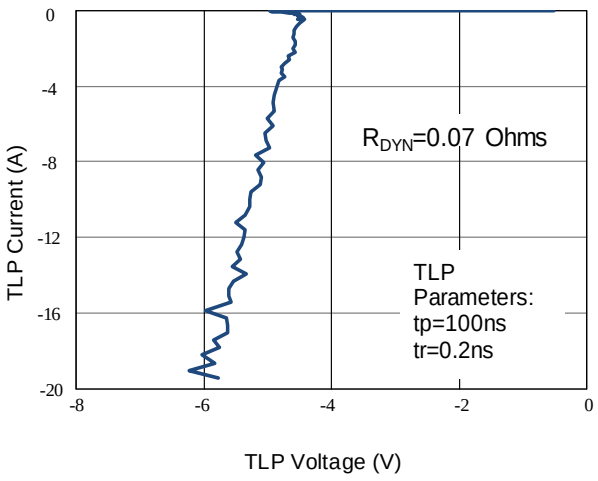
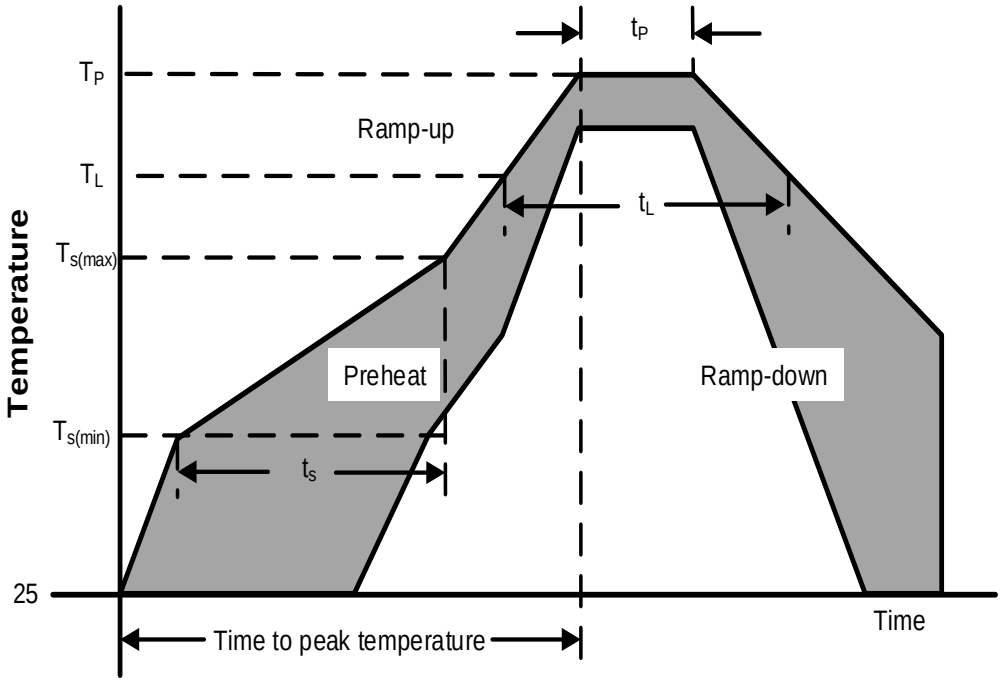


Figure 6: TLP Negative I-V Curve



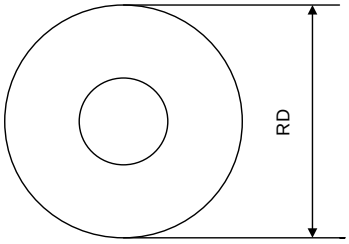
Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	Temperature Min ($T_{s(min)}$)	150°C
	Temperature Max ($T_{s(max)}$)	200°C
	Time (min to max) (ts)	60 – 190 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{S(max)}$ to T_L——Ramp-up Rate		5°C/second max
Reflow	Temperature (T_L) (Liquidus)	217°C
	Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_P)		260+0/-5 °C
Time within actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		280°C

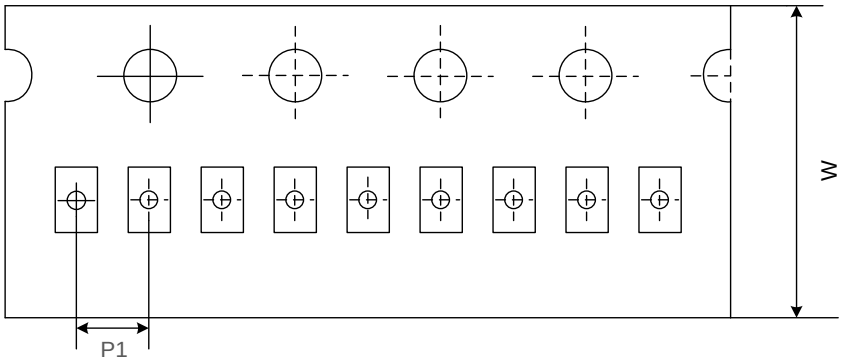


Tape And Reel Information

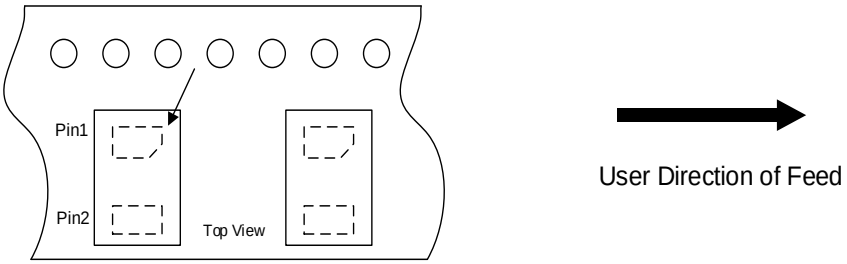
Reel Dimensions



Tape Dimensions



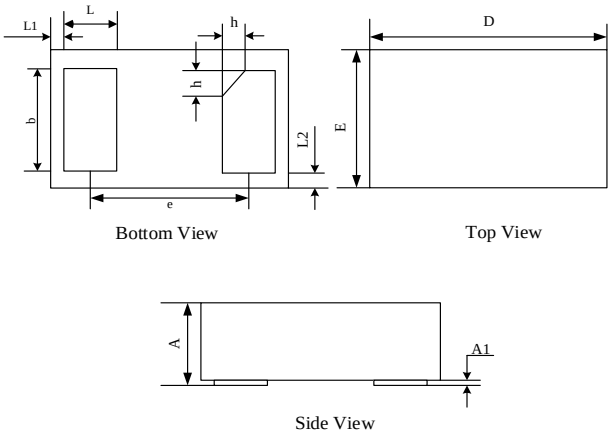
Quadrant Assignments For PIN1 Orientation In Tape



RD	Reel Dimensions	7 inch
W	Overall width of the carrier tape	8 mm
P1	Pitch between successive cavity centers	2mm

Outline Drawing –DFN1006-2L

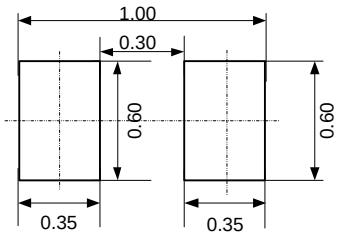
PACKAGE OUTLINE



DFN1006-2L

SYMBOL	MILLIMETERS		
	NOM	MIN	MAX
A	--	0.35	0.400
A1	--	--	0.050
D	1.020	0.990	1.050
E	0.620	0.590	0.650
b	0.480	0.430	0.530
L	0.220	0.170	0.270
h	0.125	0.075	0.175
L1	0.075REF		
L2	0.070REF		
e	0.650REF		

Land Pattern



Marking Codes

Part Number	Marking Code
WS03DPMF-BH	1 EE 2

Package Information

Qty：10k/Reel

CONTACT INFORMATION

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